## BAV199

## LOW LEAKAGE DOUBLE DIODE

For low leakage current applications

## Feature

- Very low leakage current
- Medium speed switching times
- Series pair configuration


Marking: PX
SOT-23 Plastic Package

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Peak Repetitive Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 85 | V |
| Continuous Reverse Voltage | $\mathrm{V}_{\mathrm{R}}$ | 85 | V |
| Continuous Forward Current $\begin{gathered}\text { Single Diode } \\ \text { Double Diode }\end{gathered}$ | $\mathrm{I}_{\mathrm{F}}$ | $\begin{aligned} & 160 \\ & 140 \end{aligned}$ | mA |
| Repetitive Peak Forward Current | $\mathrm{I}_{\text {FRM }}$ | 500 | mA |
| Non-Repetitive Peak Forward Surge Current at $\mathrm{t}=1 \mu \mathrm{~s}$ at $\mathrm{t}=1 \mathrm{~ms}$ at $\mathrm{t}=1 \mathrm{~s}$ | $\mathrm{I}_{\text {FSM }}$ | $\begin{gathered} 4 \\ 1 \\ 0.5 \end{gathered}$ | A |
| Power Dissipation | $\mathrm{P}_{\mathrm{D}}$ | 250 | mW |
| Thermal Resistance Junction to Ambient Air | $\mathrm{R}_{\text {日JA }}$ | 500 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Operating and Storage Temperature Range | $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Reverse Breakdown Voltage at $I_{R}=100 \mu \mathrm{~A}$ | $\mathrm{V}_{(\mathrm{BR}) \mathrm{R}}$ | 85 | - | - | V |
| $\begin{aligned} & \text { Forward Voltage } \\ & \text { at } I_{F}=1 \mathrm{~mA} \\ & \text { at } I_{F}=10 \mathrm{~mA} \\ & \text { at } I_{F}=50 \mathrm{~mA} \\ & \text { at } I_{F}=150 \mathrm{~mA} \end{aligned}$ | $V_{F}$ |  |  | $\begin{gathered} 0.9 \\ 1 \\ 1.1 \\ 1.25 \\ \hline \end{gathered}$ | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } V_{R}=75 \mathrm{~V} \\ & \text { at } V_{R}=75 \mathrm{~V}, \mathrm{~T}_{j}=150^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{R}} \\ & \mathrm{I}_{\mathrm{R}} \\ & \hline \end{aligned}$ |  | - | $\begin{gathered} 5 \\ 80 \end{gathered}$ | nA |
| Total Capacitance at $V_{R}=0, f=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {T }}$ | - | 2 | - | pF |
| Reverse Recovery Time at $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{\mathrm{R}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{rr}}=0.1 \mathrm{XI}, \mathrm{I}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\mathrm{rr}}$ | - | - | 3 | $\mu \mathrm{s}$ |



